

## DIOTEC ELECTRONICS CORP.

18020 Hobart Blvd., Unit B Gardena, CA 90248 U.S.A

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Data Sheet No. BRDB-300-1C

## 3 AMP SILICON BRIDGE RECTIFIERS

### **FEATURES**

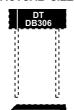
- PRV Ratings from 50 to 1000 Volts
- Surge overload rating to 60 Amps peak
- Reliable low cost molded epoxy construction
- Ideal for printed circuit board applications
- **UL RECOGNIZED FILE #E124962**
- **RoHS COMPLIANT**

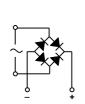
#### **MECHANICAL DATA**

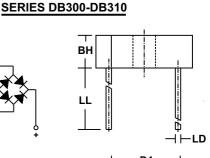
- Case: Molded Epoxy (UL Flammability Rating 94V-0)
- Terminals: Round silver plated copper pins
- Soldering: Per MIL-STD 202 Method 208 guaranteed
- Polarity: Marked on top of case; positive lead at beveled corner
- Mounting Position: Any. Thru hole provided for #6 screw (NOTE 1)
- Weight: 0.13 Ounces (3.6 Grams)

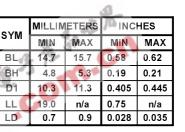
### **MECHANICAL SPECIFICATION**

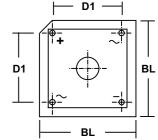
### ACTUAL SIZE











## **MAXIMUM RATINGS & ELECTRICAL CHARACTERISTICS**

BL

BH

D1

LD

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, 60Hz, resistive or inductive load. For capacitive loads, derate current by 20%.

| PARAMETER (TEST CONDITIONS)   | SYMBOL       | RATINGS              |           |           |           |           |           |            | UNITS                    |
|---|--------------|----------------------|-----------|-----------|-----------|-----------|-----------|------------|--------------------------|
| Series Number   |              | DB<br>300            | DB<br>301 | DB<br>302 | DB<br>304 | DB<br>306 | DB<br>308 | DB<br>310  |                          |
| Maximum DC Blocking Voltage   | <b>V</b> RM  |                      |           | 200       | 400       | 600       |           |            | VOLTS                    |
| Working Peak Reverse Voltage  | VRWM         |                      | 100       |           |           |           |           |            |                          |
| Maximum Peak Recurrent Reverse Voltage  | <b>V</b> RRM |                      |           |           |           |           |           |            |                          |
| RMS Reverse Voltage   | VR (RMS)     | 35                   | 70        | 140       | 280       | 420       | 560       | 700        | 1                        |
| Thermal Energy (Rating for Fusing) t < 8.3mSec  | l²t          | 15                   |           |           |           |           |           |            | AMPS <sup>2</sup><br>SEC |
| Peak Forward Surge Current. Single 60Hz Half-Sine Wave Superimposed on Rated Load (JEDEC Method). Tc = 60° C        | IFSM         | 60                   |           |           |           |           |           | AMPS       |                          |
| Average Forward Rectified Current $@ Tc = 60^{\circ}C \text{ (Note 2)}$<br>$@ T_{A} = 25^{\circ}C \text{ (Note 3)}$ | lo           | 3<br>2               |           |           |           |           |           |            |                          |
| Junction Operating and Storage Temperature Range  | TJ, TSTG     | -55 to +150          |           |           |           |           |           |            | °C                       |
| Maximum Forward Voltage (Per Diode) at 1.5 Amps DC  | VFM          | 0.95 (Typical < 0.9) |           |           |           |           |           |            |                          |
| Typical Junction Capacitance (Note 4)   | CJ           | 21                   |           |           |           |           |           | pF         |                          |
| Maximum Reverse Current at Rated V <sub>RM</sub>  | IRM          | 1<br>50              |           |           |           |           |           | μ <b>Α</b> |                          |
| Minimum Insulation Breakdown Voltage (Circuit to Case)  | <b>V</b> iso | 2500                 |           |           |           |           |           |            | VOLTS                    |
| Typical Thermal Resistance Junction to Ambient (Note 3)  Junction to Case (Note 2)                                  | R⊕JA<br>R⊕JC | 12.0<br>8.0          |           |           |           |           |           |            | °C/W                     |

NOTES: (1) Bolt bridge on heat sink with #6 screw, using silicon thermal compound between bridge and mounting surface for maximum heat transfer.
(2) Bridge mounted on 4.0" sq. x 0.11" thick (10.5cm sq. x 0.3cm) aluminum plate
(3) Bridge mounted on PC Board with 0.5" sq. (12mm sq.) copper pads and bridge lead length of 0.375" (9.5mm)
(4) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts





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### Data Sheet No. BRDB-300-2C

# **3 AMP SILICON BRIDGE RECTIFIERS**

## **RATING & CHARACTERISTIC CURVES FOR SERIES DB300 - DB310**

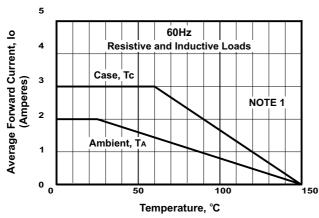


FIGURE 1. FORWARD CURRENT DERATING CURVE

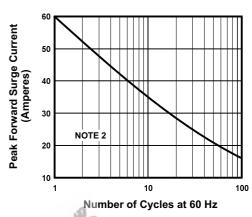


FIGURE 2. MAXIMUM NON-REPETITIVE SURGE CURRENT

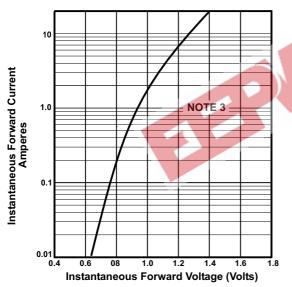
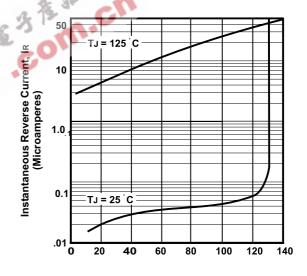


FIGURE 3. TYPICAL FORWARD CHARACTERISTIC PER DIODE



Percent of Rated Peak Reverse Voltage
FIGURE 4. TYPICAL REVERSE CHARACTERISTICS

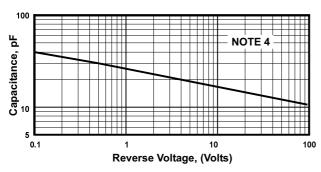


FIGURE 5. TYPICAL JUNCTION CAPACITANCE PER DIODE

## NOTES

(1) Case Temperature, Tc, With Bridge Mounted on 4" Sq. x 0.11" Thick (10.5cm Sq. x 0.3cm) Aluminum Plate

Ambient Temperature, TA, With Bridge Mounted on PC Board With 0.5" Sq. (12mm Sq.) Pads and Lead Length of 0.375" (9.5mm)

(2)  $Tc = 60^{\circ}C$ 

(3) T<sub>J</sub> = 25°C; Pulse Width = 300 Sec; 1% Duty Cycle

(4)  $T_J = 25^{\circ}C$ ; f = 1 MHz; Vsig = 50mVp-p

E14